



#### BC856AW-BC858CW

#### PNP SMALL SIGNAL TRANSISTOR IN SOT323

#### Features

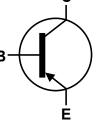
- Ideally Suited for Automatic Insertion
- Complementary NPN Types Available (BC846AW BC848CW)
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

#### **Mechanical Data**

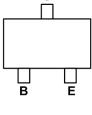
- Case: SOT323
- Case material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)



Top View







С

Top View Pin-Out

#### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel	Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC856AW-7-F	AEC-Q101	K3A	7	3,000	BC857BWQ-13-F	Automotive	K3B	13	10,000
BC856BW-7-F	AEC-Q101	K3B	7	3,000	BC857CW-7-F	AEC-Q101	K3G	7	3,000
BC856BW-13-F	AEC-Q101	K3B	13	10,000	BC858AW-7-F	AEC-Q101	K3A	7	3,000
BC857AW-7-F	AEC-Q101	K3A	7	3,000	BC858BW-7-F	AEC-Q101	K3B	7	3,000
BC857BW-7-F	AEC-Q101	K3B	7	3,000	BC858CW-7-F	AEC-Q101	K3G	7	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

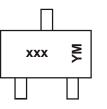
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Haloger- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

A Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. Tape width is 8mm. For packaging details, go to our website at http://www.diodes.com/products/packages.html

#### Marking Information



xxx = Product Type Marking Code (See Ordering Information) YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: A = 2013) M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key

Year	2010	20	011	2012	2	013	2014	2	2015	2016		2017
Code	Х		Y	Z		А	В		С	D		E
												1
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Νον	Dec



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteris	tic	Symbol	Value	Unit
	BC856		-80	
Collector-Base Voltage	BC857	V <sub>CBO</sub>	-50	V
	BC858		-30	
	BC856		-65	
Collector-Emitter Voltage	BC857	V <sub>CEO</sub>	-45	V
	BC858		-30	
Emitter-Base Voltage		V <sub>EBO</sub>	-5.0	V
Continuous Collector Current		lc	-100	mA
Peak Collector Current		I <sub>CM</sub>	-200	mA
Peak Emitter Current		I <sub>EM</sub>	-200	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 6)		PD	200	mW
Thermal Resistance, Junction to Ambient (Note 6)		R <sub>θJA</sub>	625	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C	

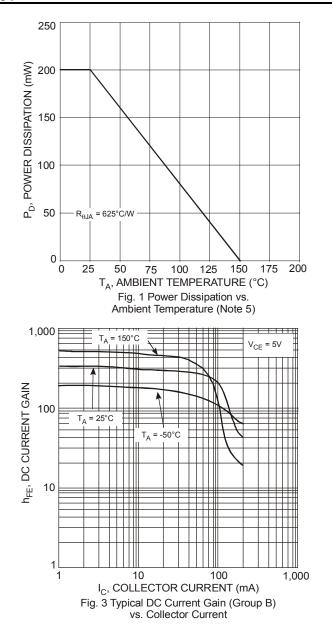
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

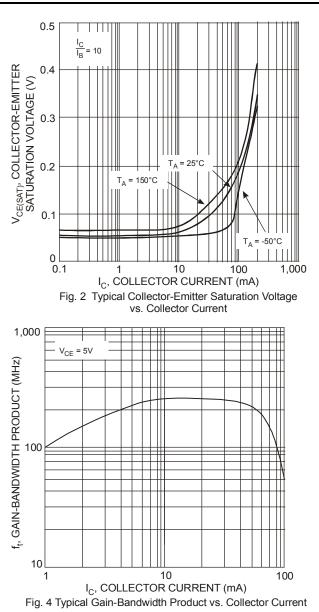
Cha	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition
		BC856	-	-80				
Collector-Base Breakdown Voltage BC857			BV <sub>CBO</sub>	-50	-	-	V	I <sub>C</sub> = -100nA
BC858			-30					
BC856				-65				
Collector-Emitter Breakdown	Collector-Emitter Breakdown Voltage (Note 7) BC857 BC858		BV <sub>CEO</sub>	-45	-	-	V	I <sub>C</sub> = -10mA
				-30				
Emitter-Base Breakdown Volt	tage		BV <sub>EBO</sub>	-5	-	-	V	I <sub>E</sub> = -100nA
		A		125	180	250		$V_{CE}$ = -5.0V, I <sub>C</sub> = -2.0mA
DC Current Gain (Note 7)	Current Gain Grou		h <sub>FE</sub>	220	290	475	-	
		С		420	520	800		
Collector Cutoff Current			I <sub>CBO</sub>	-	-	-15	nA	V <sub>CB</sub> = -30V
				-		-4	μA	V <sub>CB</sub> = -30V, T <sub>A</sub> = +150°C
Collector Emitter Seturation )	(altara (Nata 7)		V <sub>CE(sat)</sub>		-75	-300	mv	I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA
Collector-Emitter Saturation \	Vollage (Note 7)			-	-250	-650		I <sub>C</sub> = -100mA, I <sub>B</sub> = -5.0mA
Read Emitter Turn On Voltag	o (Nieto 7)		N/	-600	-650	-750	mV	I <sub>C</sub> = -2mA, V <sub>CE</sub> = -5V
Base-Emitter Turn-On Voltag	e (Note 7)		V <sub>BE(on)</sub>	-	-	-820		I <sub>C</sub> = -10mA, V <sub>CE</sub> = -5V
Doop Emitter Seturation Volta	ana (Niata 7)		N/	-	-700	-	mV	I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA
Base-Emitter Saturation Volta	age (Note 7)		V <sub>BE(sat)</sub>		-850	-950		I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA
Output Capacitance			C <sub>obo</sub>	-	3	4.5	pF	V <sub>CB</sub> = -10V, f = 1.0MHz
Transition Frequency			f <sub>T</sub>	100	200	-	MHz	V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA, f = 100MHz
Noise Figure			NF	-	-	10	dB	V <sub>CE</sub> = -5V, I <sub>C</sub> = -200μA R <sub>S</sub> = 2kΩ, f = 1kHz ∆f = 200Hz

6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2% Notes:



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

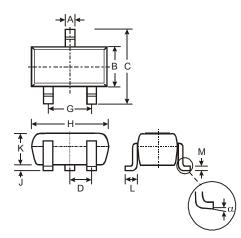






## **Package Outline Dimensions**

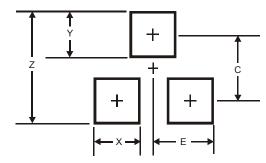
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT323							
Dim	Min	Max	Тур					
Α	0.25	0.40	0.30					
в	1.15	1.35	1.30					
C	2.00	2.20	2.10					
D	-	-	0.65					
G	1.20	1.40	1.30					
н	1.80	2.20	2.15					
J	0.0	0.10	0.05					
κ	0.90	1.00	1.00					
L	0.25	0.40	0.30					
М	0.10	0.18	0.11					
α	0°	8°	-					
All	Dimens	ions in	mm					

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0



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